

/ Descriptions

TO-92(R) NPN Silicon NPN transistor in a TO-92(R) Plastic Package.

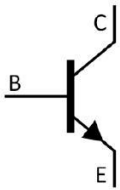
/ Features

High Voltage, Low Noise.

/ Applications

Low noise amplifier application.

/ Equivalent Circuit



/ Pinning



 PIN1 Emitter
  PIN 2 Base
  PIN 3 Collector

/ h_{FE} Classifications & Marking

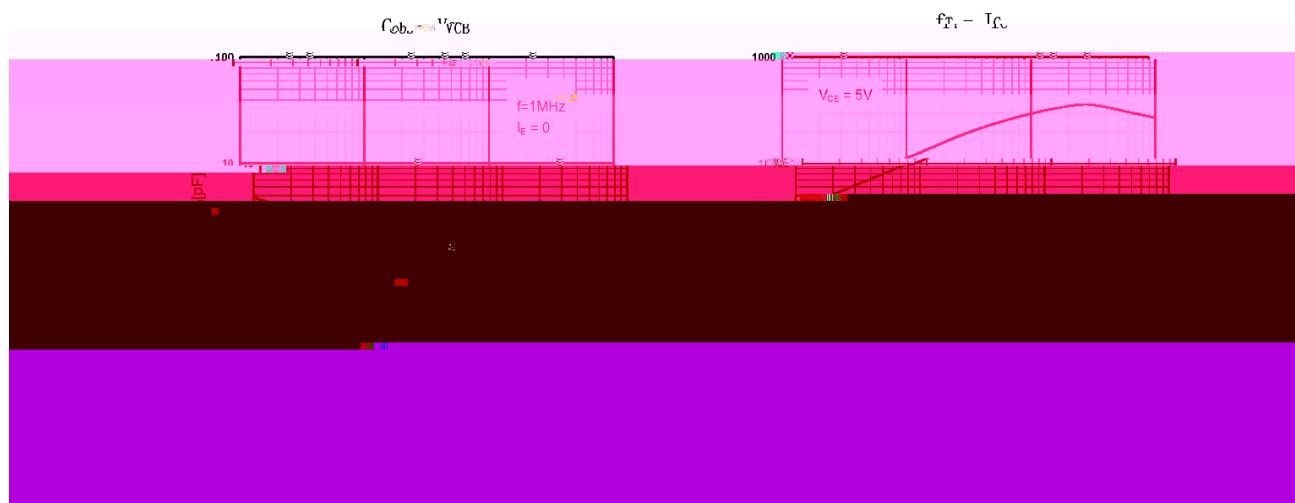
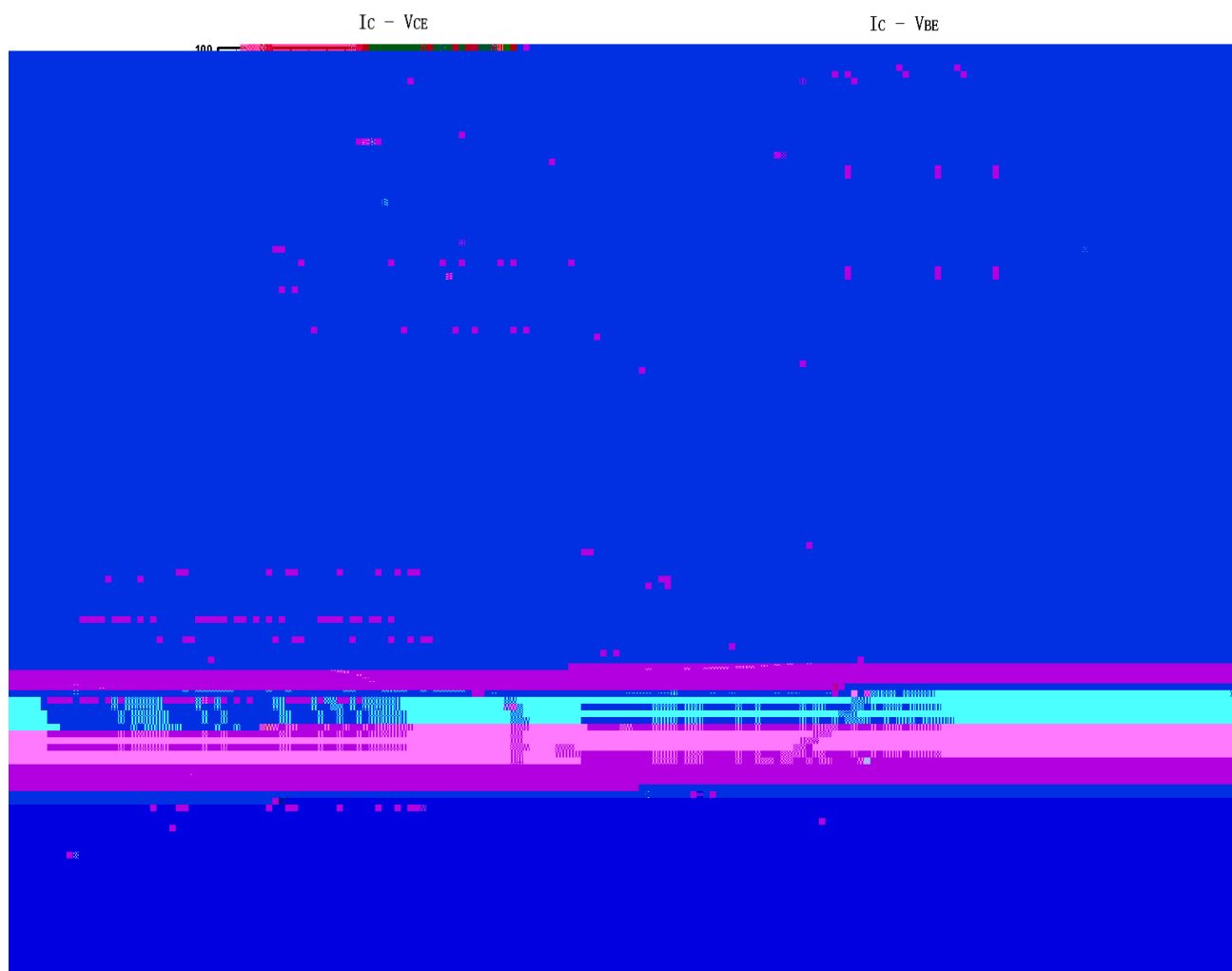
h_{FE} Classifications Symbol	A	B	C
h_{FE} Range	110 220	200 450	420 800

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	50	V
Collector to Emitter Voltage	V_{CEO}	45	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	100	mA
Collector Power Dissipation	P_C	625	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

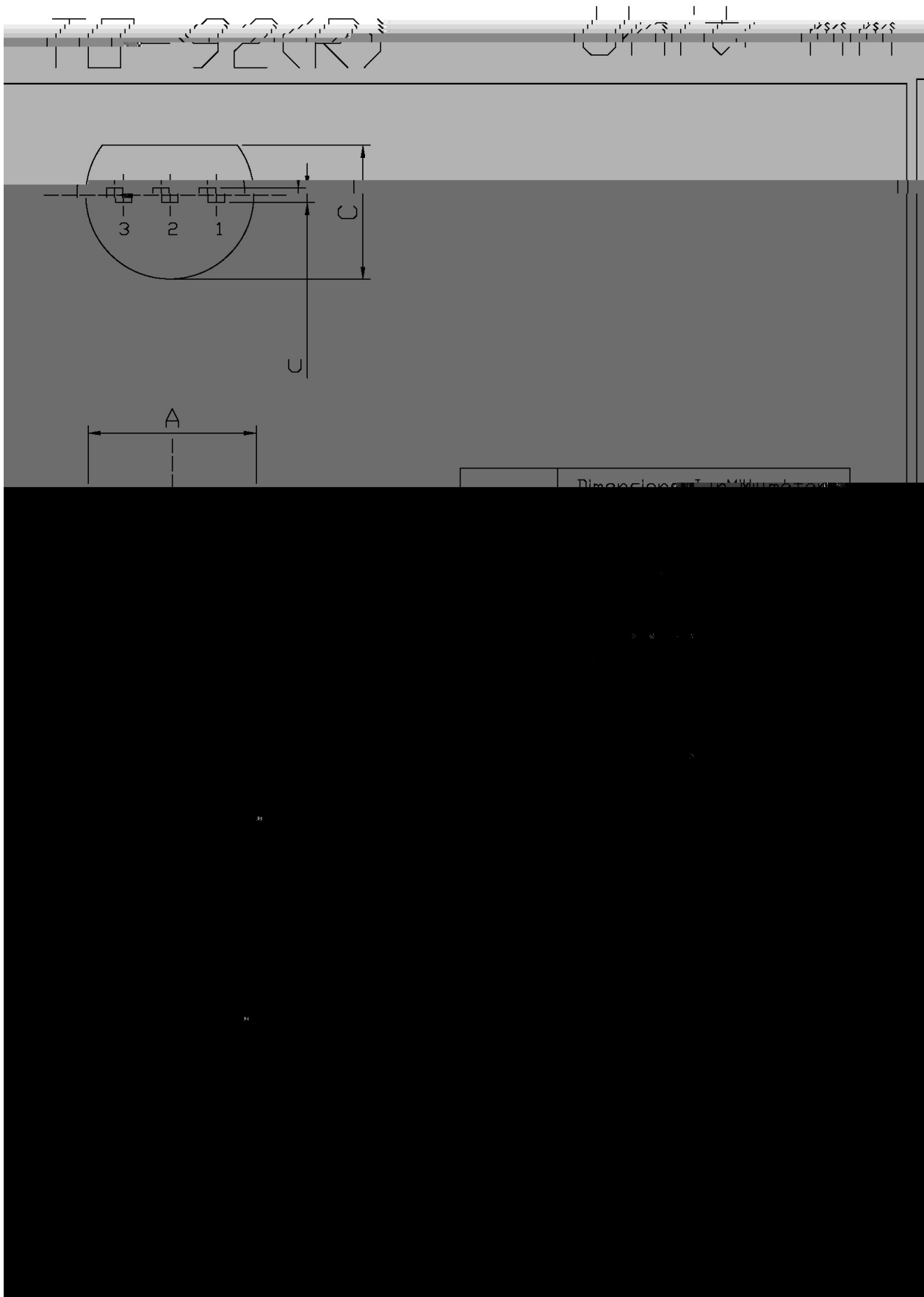
/ Electrical Characteristics($T_a=25^\circ\text{C}$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Emitter Breakdown						

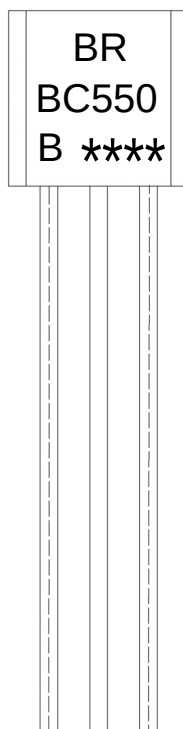
/ **Electrical Characteristic Curve**



/ Package Dimensions



/ Marking Instructions



BR

BC550

B

h_{FE}

Note:

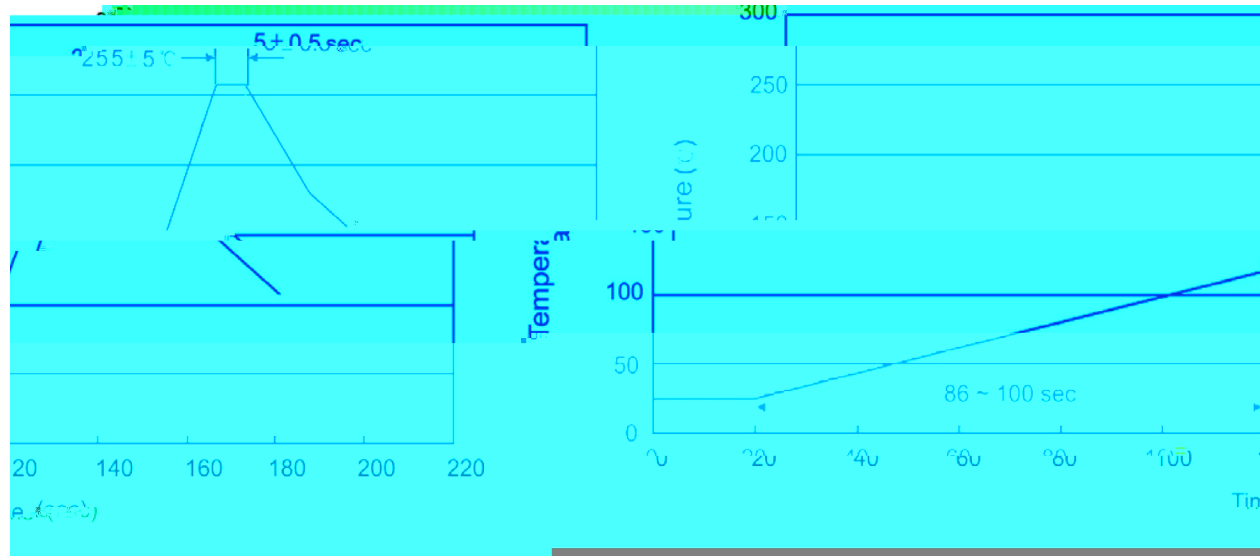
BR: Company Code.

BC550: Product Type.

B h_{FE} Classifications Symbol

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- 1

25 150

60 90sec;
- 2

255±5

5±0.5sec;
- 3

2 10 /sec.
- 1.Preheating:25~150 , Time:60~90sec.

2.Peak Temp.:255±5 , Duration:5±0.5sec.

3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

270±5 10±1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type		Units				Dimension		(unit mm3)
34	T5W67-60	Units/Bag	Bags/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Bag0	100028214
0		100028214	1	336	167-60	182		100028214